



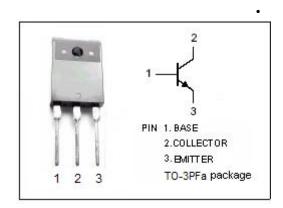
isc Silicon NPN Power Transistor

DESCRIPTION

- · Collector-Base Breakdown Voltage-
 - : V_{(BR)CBO}= 900V(Min.)
- Wide Area of Safe Operation
- · High Speed Switching
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

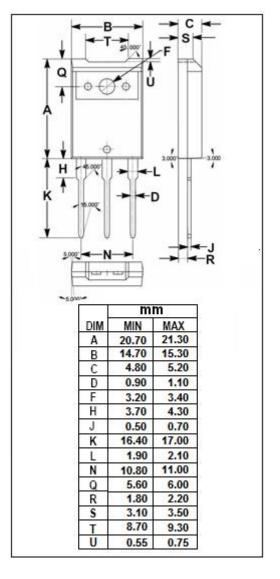
APPLICATIONS

· Designed for high speed switching applications.



ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	900	V	
V _{CES}	Collector-Emitter Voltage	900	V	
V _{CEO}	Collector-Emitter Voltage	800	V	
V _{EBO}	Emitter-Base Voltage	7	V	
Ic	Collector Current-Continuous	5	А	
Ісм	Collector Current-Peak	10	А	
Ι _Β	Base Current-Continuous	3	А	
Pc	Collector Power Dissipation @T _a =25℃	3	W	
	Collector Power Dissipation @T _C =25°C	80		
T _j	Junction Temperature	150	$^{\circ}$ C	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$ C	



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2SC3981

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	800			V		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 3A; I _B = 0.6A			1.5	V		
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 3A; I _B = 0.6A			1.5	V		
I _{CBO}	Collector Cutoff Current	V _{CB} = 900V; I _E = 0			50	μ А		
I _{EBO}	Emitter Cutoff Current	V _{EB} = 7V; I _C = 0			50	μ А		
h _{FE-1}	DC Current Gain	I _C = 0.1A; V _{CE} = 5V	8					
h _{FE-2}	DC Current Gain	I _C = 3A; V _{CE} = 5V	6					
f _T	Current-Gain—Bandwidth Product	I _C = 0.5A; V _{CE} = 5V; f= 1MHz		15		MHz		
Switching Times								
t _{on}	Turn-on Time				0.7	μS		
ts	Storage Time	I _C = 3A; I _{B1} = 0.6A; I _{B2} = -1.2A; V _{CC} = 250V			2.5	μS		
t _f	Fall Time				0.3	μs		

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